

# SANYO Semiconductors DATA SHEET

# 2SK3617—General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		6	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	24	Α
Allowable Power Dissipation	D-		1	W
	PD	Tc=25°C	15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>G</sub> S=0	100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A	3	5		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =3A, V <sub>GS</sub> =10V		180	225	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =3A, V <sub>GS</sub> =4V		225	315	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		530		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		45		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		35		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		9		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		5		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		54		ns
Fall Time	tf	See specified Test Circuit.		25		ns

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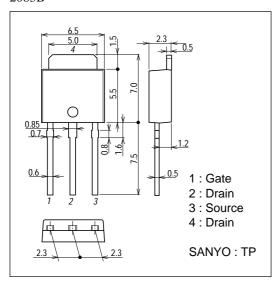
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	] Oill
Total Gate Charge	Qg	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		13		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		2.1		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		2.8		nC
Diode Forward Voltage	V <sub>SD</sub>	IS=6A, VGS=0		0.9	1.2	V

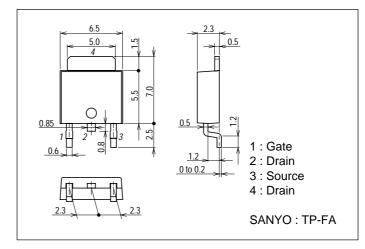
# **Package Dimensions**

unit : mm 2083B

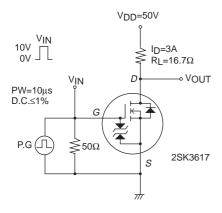


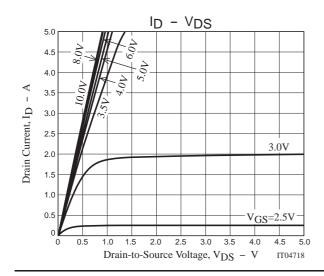
### **Package Dimensions**

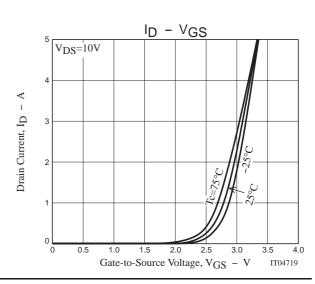
unit : mm 2092B

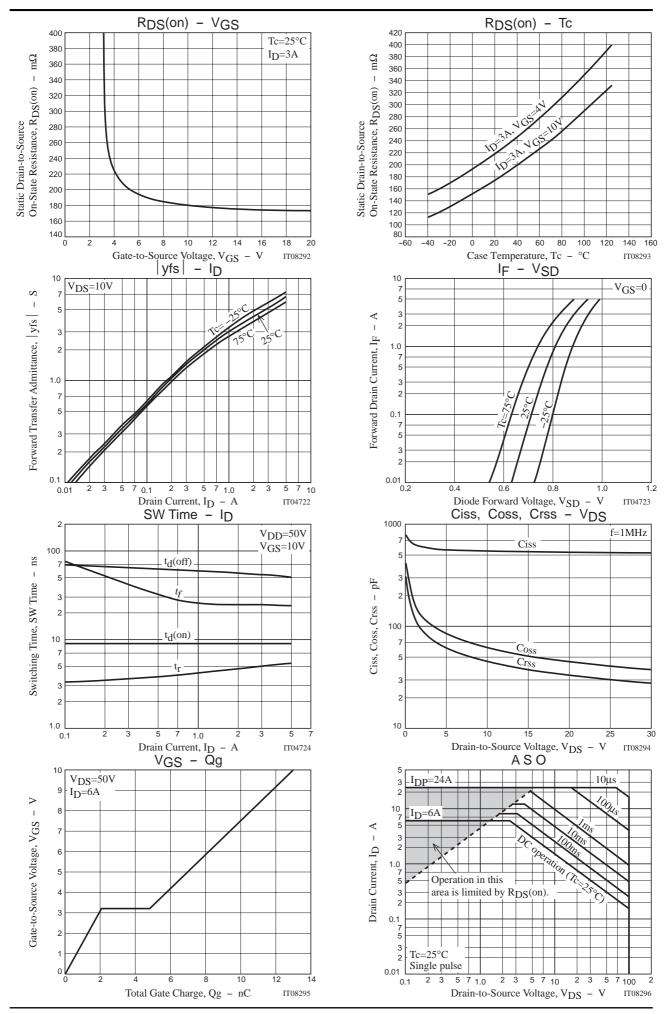


# **Switching Time Test Circuit**

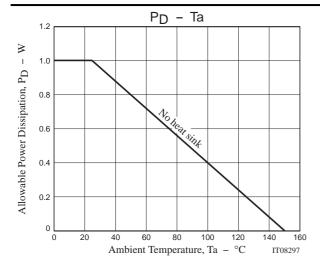


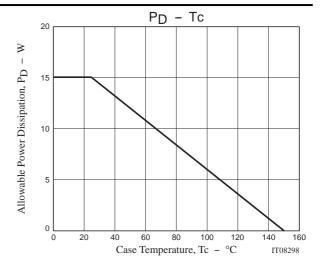






#### 2SK3617





Note on usage: Since the 2SK3617 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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